W-CDMA 2100 MHz to 2200 MHz power MMIC

Rev. 4 — 7 March 2011

**Product data sheet** 

## 1. Product profile

### 1.1 General description

30 W LDMOS 2-stage power MMIC for base station applications at frequencies from 2100 MHz to 2200 MHz. Available in gull wing for surface mount (SOT822-1) or flat lead (SOT834-1).

#### Table 1.Typical performance

Typical RF performance at  $T_h = 25$  °C.

Mode of operation	f	$V_{\text{DS}}$	P <sub>L(AV)</sub>	Gp	η <b>D</b>	IMD3	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)
2-carrier W-CDMA	2110 to 2170	28	2	29.5	9	-48 <mark>[1]</mark>	-50 <mark>[1]</mark>

[1] Test signal: 3GPP; test model 1; 64 DPCH; PAR = 7 dB at 0.01 % probability on CCDF per carrier; carrier spacing 10 MHz.

#### CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

### 1.2 Features and benefits

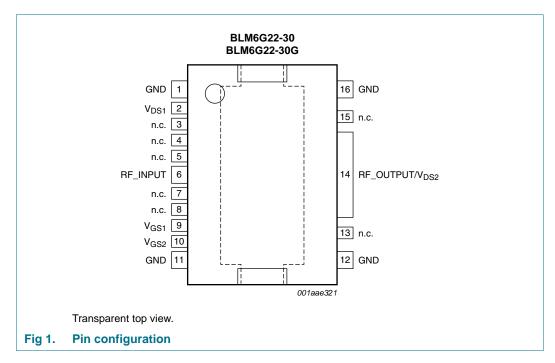
- Typical 2-carrier W-CDMA performance at a frequency of 2110 MHz:
  - Average output power = 2 W
  - Power gain = 30 dB (typ)
  - Efficiency = 9 %
  - ♦ IMD3 = -48 dBc
  - ACPR = -50 dBc
- Integrated temperature compensated bias
- Excellent thermal stability
- Biasing of individual stages is externally accessible
- Integrated ESD protection
- Small component size, very suitable for PA size reduction
- On-chip matching (input matched to 50 Ohm, output partially matched)
- High power gain
- Designed for broadband operation (2100 MHz to 2200 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)



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## 2. Pinning information

### 2.1 Pinning



### 2.2 Pin description

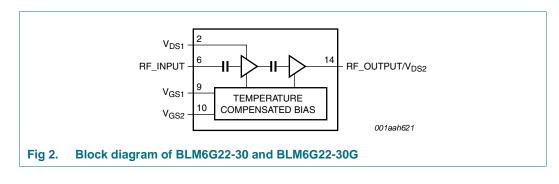
Symbol	Pin	Description
GND	1, 11, 12, 16	ground
V <sub>DS1</sub>	2	first stage drain-source voltage
n.c.	3, 4, 5, 7, 8, 13, 15	not connected
RF_INPUT	6	RF input
V <sub>GS1</sub>	9	first stage gate-source voltage
V <sub>GS2</sub>	10	second stage gate-source voltage
RF_OUT/V <sub>DS2</sub>	14	RF output or second stage drain-source voltage
RF GND	flange	RF ground

## 3. Ordering information

Table 3. Ordering information						
Type number Package						
	Name	Description	Version			
BLM6G22-30	HSOP16F	plastic, heatsink small outline package; 16 leads (flat)	SOT834-1			
BLM6G22-30G	HSOP16	plastic, heatsink small outline package; 16 leads	SOT822-1			

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## 4. Block diagram



## 5. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage		-	65	V
V <sub>GS</sub>	gate-source voltage		0.5	+13	V
I <sub>D1</sub>	first stage drain current		-	3	А
I <sub>D2</sub>	second stage drain current		-	9	А
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

## 6. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Value	Unit
R <sub>th(j-c)1</sub>	first stage thermal resistance from junction to case	$T_{case} = 25 \text{ °C}; P_L = 2 \text{ W};$ 2-carrier W-CDMA	[1] 3.9	K/W
R <sub>th(j-c)2</sub>	second stage thermal resistance from junction to case	$T_{case} = 25 \text{ °C}; P_L = 2 \text{ W};$ 2-carrier W-CDMA	<u>[1]</u> 2.1	K/W

[1] Thermal resistance is determined under specific RF operating conditions.

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## 7. Characteristics

#### Table 6. Characteristics

Mode of operation: 2-carrier W-CDMA; PAR 7 dB at 0.01 % probability on CCDF; 3GPP test model 1; 1-64 PDPCH;  $f_1 = 2112.5$  MHz;  $f_2 = 2122.5$  MHz;  $f_3 = 2157.5$  MHz;  $f_4 = 2167.5$  MHz;  $V_{DS} = 28$  V;  $I_{Dq1} = 270$  mA;  $I_{Dq2} = 280$  mA;  $T_h = 25$  °C unless otherwise specified; in a production test circuit as described in <u>Section 9 "Test information</u>".

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 2 W$	27.5	30	32.5	dB
RL <sub>in</sub>	input return loss	$P_{L(AV)} = 2 W$	-	-14	-10	dB
$\eta_D$	drain efficiency	$P_{L(AV)} = 2 W$	7.5	9	-	%
IMD3	third-order intermodulation dis	tortion $P_{L(AV)} = 2 W$	-	-48	-44.5	dBc
ACPR	adjacent channel power ratio	$P_{L(AV)} = 2 W$	-	-50	-47	dBc

## 8. Application information

#### 8.1 Ruggedness

The BLM6G22-30 and BLM6G22-30G are capable of withstanding a load mismatch corresponding to VSWR = 5 : 1 through all phases under the following conditions: V<sub>DS</sub> = 28 V;  $I_{Dq1}$  = 270 mA;  $I_{Dq2}$  = 280 mA;  $P_L$  = 2 W; 2-carrier W-CDMA.

### 8.2 Impedance information

Table 7.	Typical impedance		
f		Z <sub>i</sub> [1]	Z <sub>L</sub> <sup>[2]</sup>
MHz		Ω	Ω
2075		40.9 + j22.8	18.0 – j5.5
2085		41.2 + j23.2	17.8 – j5.6
2095		41.6 + j23.3	17.7 – j5.7
2105		41.9 + j23.3	17.7 – j5.9
2115		42.1 + j23.3	17.6 – j6.0
2125		42.2 + j23.2	17.4 – j6.0
2135		42.4 + j23.1	17.3 – j6.1
2145		42.3 + j22.9	17.2 – j6.1
2155		42.5 + j22.8	17.0 – j6.2
2165		42.6 + j22.8	16.8 – j6.3
2175		42.7 + j22.8	16.6 – j6.4
2185		43.0 + j23.0	16.4 – j6.6
2195		43.6 + j23.1	16.3 – j6.9
2205		44.2 + j23.3	16.1 – j7.2

[1] Device input impedance as measured from gate to ground.

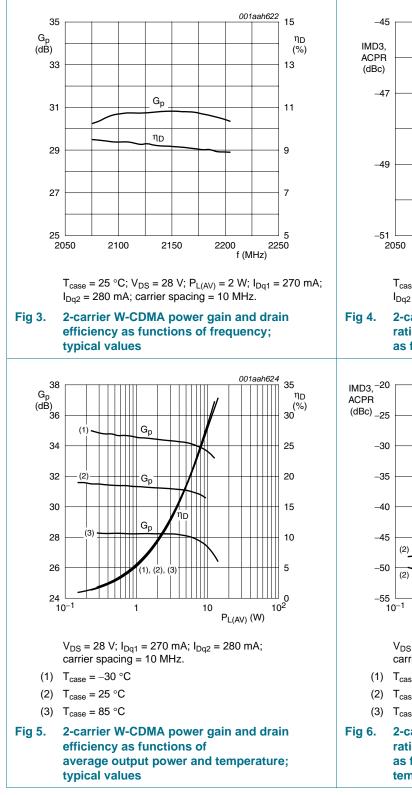
[2] Test circuit impedance as measured from drain to ground.

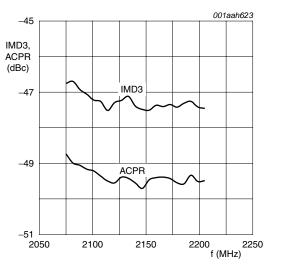
BLM6G22-30\_BLM6G22-30G

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#### 8.3 Performance curves

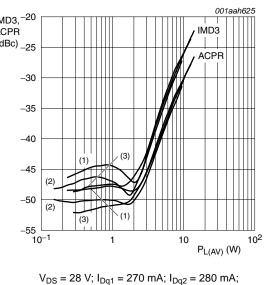
Performance curves are measured in a BLM6G22-30G application circuit.





 $T_{case} = 25 \text{ °C}; V_{DS} = 28 \text{ V}; P_{L(AV)} = 2 \text{ W}; I_{Dq1} = 270 \text{ mA};$  $I_{Dq2} = 280 \text{ mA}$ ; carrier spacing = 10 MHz.

#### 2-carrier W-CDMA adjacent power channel ratio and third order intermodulation distortion as functions of frequency; typical values



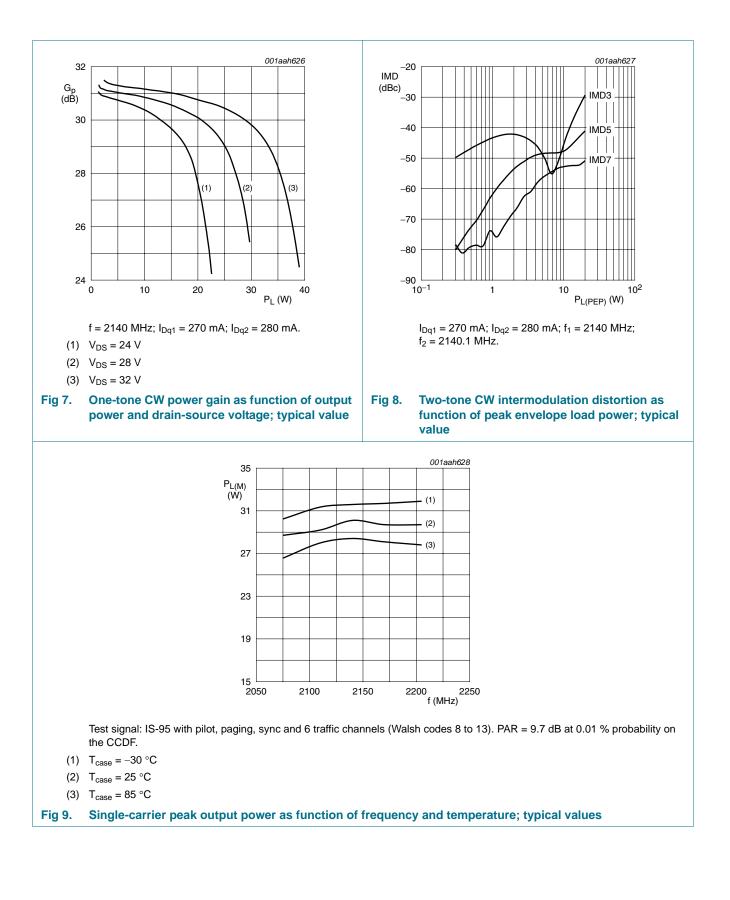
carrier spacing = 10 MHz.

- (1)  $T_{case} = -30 \degree C$
- (2) T<sub>case</sub> = 25 °C
- (3) T<sub>case</sub> = 85 °C
- 2-carrier W-CDMA adjacent power channel ratio and third order intermodulation distortion as functions of average output power and temperature; typical values

### **NXP Semiconductors**

# BLM6G22-30; BLM6G22-30G

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## 9. Test information

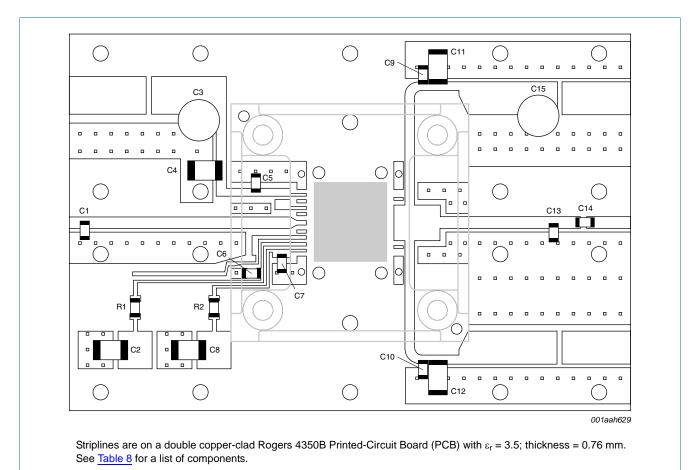


Fig 10. Component layout for 2110 MHz to 2170 MHz circuit for 2-carrier W-CDMA

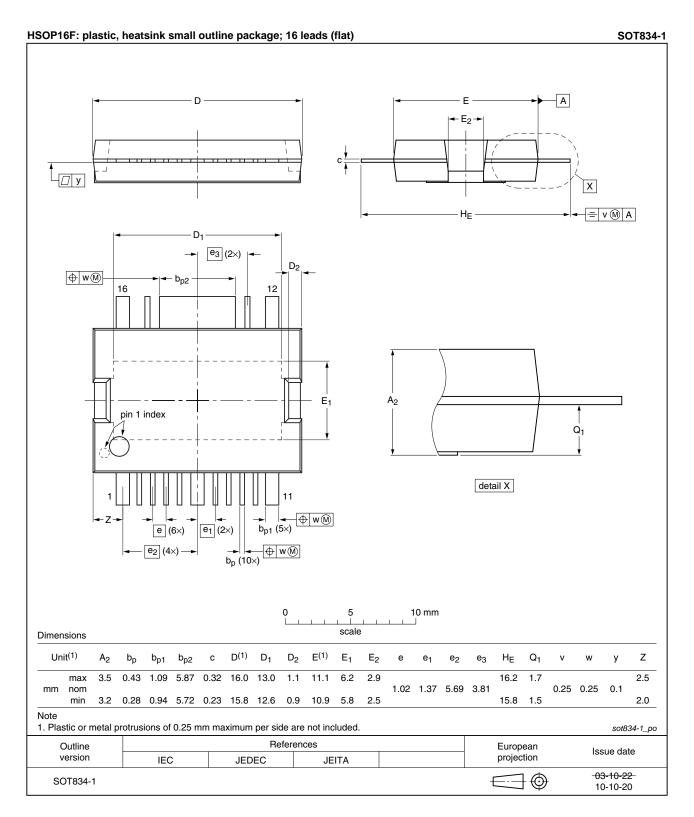
# Table 8.List of componentsFor test circuit see Figure 10.

Component	Description	Value	Remarks
C1, C13	multilayer ceramic chip capacitor	0.3 pF	[1]
C2, C4, C8, C11, C12	multilayer ceramic chip capacitor	4.7 μF; 50 V	
C3, C15	electrolytic capacitor	220 μF; 35 V	
C5, C9, C10, C14	multilayer ceramic chip capacitor	10 pF	[1]
C6, C7	multilayer ceramic chip capacitor	100 nF	
R1	SMD resistor 0805	1 kΩ	
R2	SMD resistor 0805	3.9 kΩ	

[1] American Technical Ceramics (ATC) type 100A or capacitor of same quality.

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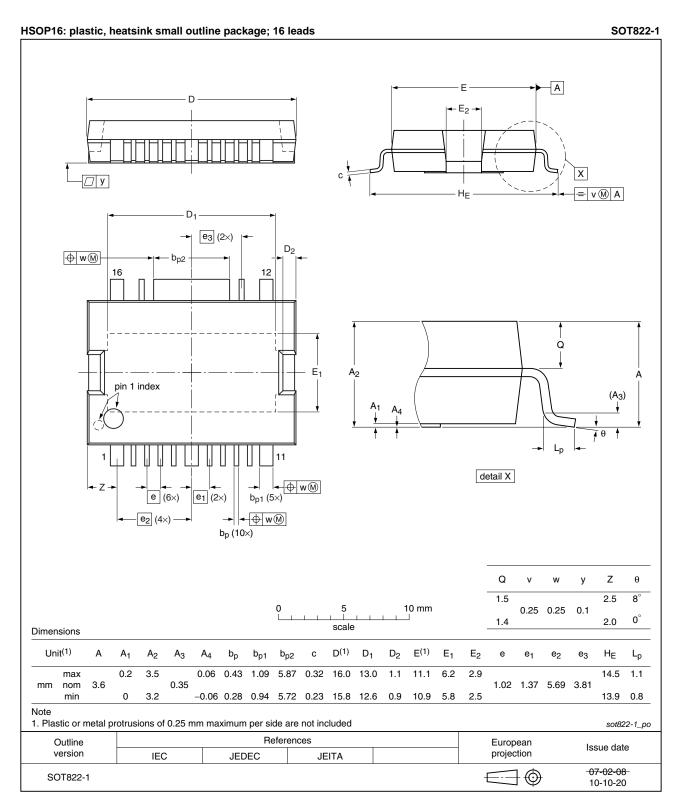
## 10. Package outline



#### Fig 11. Package outline SOT834-1 (HSOP16F)

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#### Fig 12. Package outline SOT822-1 (HSOP16)

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# **11. Handling information**

## 11.1 ESD protection

Table 9.	ESD protection characteristics				
Test cond	lition	Class			
Human Bo	ody Model (HBM)	1			
Machine M	Nodel (MM)	1			

### 11.2 Moisture sensitivity

Table 10. Moisture sensitivity level	
Test methodology	Class
JESD-22-A113	3

## **12. Abbreviations**

Table 11.	Abbreviations
Acronym	Description
3GPP	Third Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MMIC	Monolithic Microwave Integrated Circuit
PA	Power Amplifier
PAR	Peak-to-Average power Ratio
PDPCH	transmission Power of the Dedicated Physical CHannel
RF	Radio Frequency
VSWR	Voltage Standing-Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

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# **13. Revision history**

Table 12. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
BLM6G22-30_BLM6G22-30G v.4	20110307	Product data sheet	-	BLM6G22-30_BLM6G22-30G v.3
Modifications:		t status has been changen page 4: the values of R		ta sheet" picted on a negative scale
BLM6G22-30_BLM6G22-30G v.3	20081121	Preliminary data sheet	-	BLM6G22-30_BLM6G22-30G v.2
BLM6G22-30_BLM6G22-30G v.2	20080904	Preliminary data sheet	-	BLM6G22-30_BLM6G22-30G v.1
BLM6G22-30_BLM6G22-30G v.1	20080303	Objective data sheet	-	-

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## 14. Legal information

#### 14.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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